NSN 5961-01-141-5645

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-141-5645 **Inclosure Material:** Metal **Overall Length:** Between 0.330 inches and 0.505 inches **End Application:** Instrumentati 02750 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 gate trigger voltage, instantaneous and 600.0 off-state voltage, rms total **Current Rating Per Characteristic:** 100.00 milliamperes forward current, total rms peak **Maximum Operating Tempurature Per Measurement Point:** 115.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronics supply center production standrd no. L03204; for n avy nuclear propulion plant products only **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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Yes - demil/mli